VS-VSKCS200/045

Vishay Semiconductors





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PRIMARY CHARACTERISTICS					
I _{F(AV)}	200 A				
V _R	45 V				
Package	AAP Gen 7 (TO-240AA)				
Circuit configuration	Two diodes common cathode				

MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL pending
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKCS200/45 Schottky rectifier common cathode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	200	А				
V _{RRM}		45	V				
I _{FSM}	t _p = 5 μs sine	12 800	А				
V _F	100 A _{pk} , T _J = 125 °C	0.73	V				
TJ	Range	-55 to +150	°C				

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-VSKCS200/045	UNITS				
Maximum DC reverse voltage	V _R	45	V				
Maximum working peak reverse voltage	V _{RWM}	45	v				

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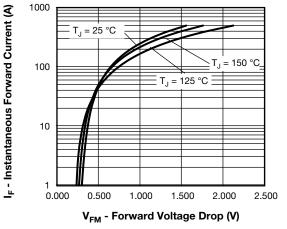
ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDI	VALUES	UNITS		
Maximum average per module			50 % duty cycle at T_{C} = 91 °C,	200			
forward current	per leg	I _{F(AV)}	50% duty cycle at $1^\circ_{\rm C} = 91^\circ_{\rm C}$,	100	1		
Maximum peak one cycle non-repetitive surge current		1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	12 800	A	
		IFSM	10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	1700		
Non-repetitive avalanche energ	ау	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 19 \text{ A}, L = 1 \text{ mH}$		180	mJ	
Repetitive avalanche current		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		15	А	

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS			
		100 A	T.I = 25 °C	0.67	V		
Maximum forward voltage drop	V	200 A	1j=25 C	0.92			
Maximum forward voltage drop	V _{FM}	100 A	T _{.1} = 125 °C	0.73			
		200 A	$1_{\rm J} = 125$ C	1.14			
Maximum reverse leakage current	I _{RM}	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	10	mA		
Maximum reverse leakage current		T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	800			
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal rang	5200	pF			
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		7.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs			
Maximum RMS insulation voltage	V _{INS}	50 Hz	3000 (1 min) 3600 (1 s)	V			

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range)	T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, junction to case per leg Typical thermal resistance, case to heatsink per module		R _{thJC}	DC operation	0.52	°C/W	
		R _{thCS}		0.1	0/00	
Approvimate weight				75	g	
Approximate weight				2.7	oz.	
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm	
	busbar		spread of the compound.	3	INIT	
Case style			JEDEC [®]	TO-240AA co	mpatible	

VS-VSKCS200/045

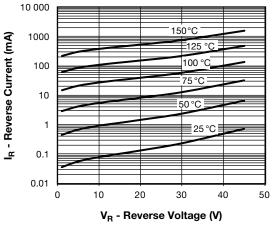
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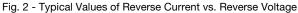


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Fig. 1 - Maximum Forward Voltage Drop Characteristics





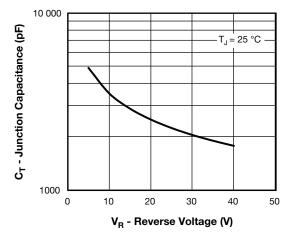


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

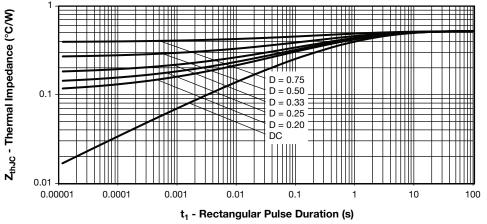
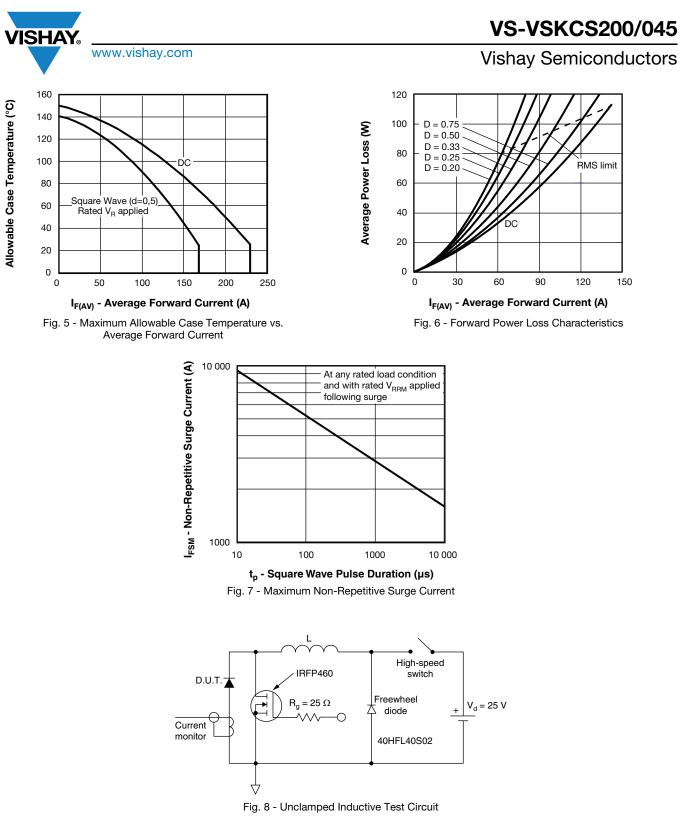


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 D)$; I_R at V_{R1} = 80 % rated V_R

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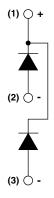
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ORDERING INFORMATION TABLE

					1	1	
Device code	vs-vs	кс	S	20	0	1	045
	1	2	3	4	5		6
	1 2 3 4 5 6	- Circ KC - S = - Ave - Pro	hay Sen cuit conf = ADD- Schottk erage cu duct silie tage rati	iguratior A-PAK - y diode rrent rat	n: 2 diode ing (20 ntificatio	es comr = 200 A n	non cathc

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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25.330.1653.1 25.	.330.4753.1	25.330.5253.1	25.334.3253.1	25.334.3353.1	25.350.2053.0	25.352.4753.1	25.522.3253.0	<u>T483C</u> <u>T484C</u>
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